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Proceedings of the Annual Meeting of the Cognitive Science Society

Title

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Permalink

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Journal

Proceedings of the Annual Meeting of the Cognitive Science Society, 39(0)

Authors

Engelmann, Felix

Kolak, Joanna

Granlund, Sonia

et al.

Publication Date

2017

Peer reviewed

The acquisition of verb morphology in Polish and Finnish: Model and experiment

Felix Engelmann

University of Manchester, Manchester, United Kingdom

Joanna Kolak

University of Manchester, Manchester, United Kingdom

Sonia Granlund

University of Liverpool, Liverpool, United Kingdom

Ben Ambridge

University of Liverpool, Liverpool, United Kingdom

Julian Pine

University of Liverpool, Liverpool, United Kingdom

Anna Theakston

University of Manchester, Manchester, United Kingdom

Elena Lieven

University of Manchester, Manchester, United Kingdom

Abstract: Usage-based approaches suggest that language acquisition is a function of the statistical properties of the input. We compare predictions from neural network models with results of two elicited-production experiments on verb inflection with children in the morphologically complex languages Polish and Finnish. Three-layer neural networks were trained to produce person/number-inflected present-tense verb forms in Polish and Finnish from phoneme representations of verb stems using frequency information from child-directed speech corpora. Simulated acquisition in both languages was affected by token frequency and phonological neighbourhood density (PND) as well as an interaction such that low-frequency forms benefited more from PND than high-frequency forms. Suffix errors showed overgeneralisation and substitutions of low-frequency forms with higher-frequency forms. The model predictions are consistent with our empirical findings, except for the frequency X PND interaction. We discuss the experimental and simulated data and their implications.